NSN 5962-01-058-6739

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View Online at https://aerobasegroup.com/nsn/5962-01-058-6739

| Body Length: |
|--|
| Between 0.370 inches and 0.434 inches |
| Body Width: |
| Between 0.240 inches and 0.290 inches |
| Body Height: |
| Between 0.049 inches and 0.090 inches |
| Maximum Power Dissipation Rating: |
| 660.0 milliwatts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| Radar set type an/aps-125 |
| Features Provided: |
| Hermetically sealed and monolithic and programmable and programmed and w/enable and w/buffered output |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Flat pack |
| Output Logic Form: |
| Transistor-transistor logic |
| Input Circuit Pattern: |
| 10 input |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| 5.5 volts power source |
| Time Rating Per Chacteristic: |
| 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output and 60.00 nanoseconds. |
| output |
| Memory Device Type: |
| Rom |
| Memory Capacity: |
| Unknown |
| Special Features: |
| Bit pattern table no. 6 |
| Test Data Document: |
| 27963-57991100 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing |
| etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) |

N/a

16 flat leads

Shelf Life:

Terminal Type And Quantity:

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|--|--|--|------|--|
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Demilitarization:

Yes - demil/mli

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